

PATENT 0717-0446P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant:

Atsushi SHIMONAKA

Conf.:

8768

Appl. No.:

09/670,820

Group:

2815

Filed:

September 28, 2000

Examiner: LANDAU

For:

SEMICONDUCTOR LASER ELEMENT AND ELECTRONIC DEVICE USING THE SAME

LARGE ENTITY TRANSMITTAL FORM

Assistant Commissioner for Patents Washington, DC 20231

January 27, 20,03

Sir:

Transmitted herewith is an amendment in the above-identified application.

The enclosed document is	s being	transmitted via	the Certificate
 of Mailing provisions o	of 37 C.	F.R. § 1.8.	

The enclosed document is being transmitted via facsimile.

The fee has been calculated as shown below:

	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR		PRESENT EXTRA	RATE	ADDITIONAL FEE
TOTAL	18	-	27	=	0	\$18	\$0.00
INDEPENDENT	2	-	3	=	0	\$84	\$0.00
FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$280	\$0.00
						TOTAL	\$0.00

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\boxtimes	Petition for two (2) month(s) extension of time pursuant to 37 C.F.R. §§ 1.17 and 1.136(a). \$410.00 for the extension of time.
	No fee is required.
\boxtimes	Check(s) in the amount of \$410.00 is(are) enclosed.
	Please charge Deposit Account No. 02-2448 in the amount of \$0.00. This form is submitted in triplicate.
over requ	If necessary, the Commissioner is hereby authorized in this, urrent, and future replies, to charge payment or credit any payment to Deposit Account No. 02-2448 for any additional fees ired under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; icularly, extension of time fees. Respectfully submitted,
	Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

Terrell C. Birch,

TCB/WLG/sjl 0717-0446P

Attachment(s)

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(Rev. 10/15/02)

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AMENDMENT

Assistant Commissioner for Patents Washington, DC 20231

January 27, 2003

Sir:

In response to the Office Action dated August 28, 2002, the period for response being extended to January 28, 2003, please amend the aboveidentified patent application as follows.

IN THE SPECIFICATION

Please replace the paragraph beginning on page 34, line 16 and ending on page 35, line 7, with the following rewritten paragraph:

Figure 6 is a perspective view showing a semiconductor laser device 20 according to embodiment 3 of the present invention. The semiconductor laser device 20 includes a semiconductor substrate 21 made of n-type GaAs. The semiconductor substrate 21 has a rectangular surface in which the longitudinal length is 1096 μm , and the width is 30 μm . (Hereinafter, the longitudinal direction of the semiconductor substrate 21 and the direction of